SP3T AIGaAs PIN Diode Switch



MA4AGSW3

Rev. V9

Features

- Ultra Broad Bandwidth: 50 MHz to 50 GHz
- Functional Bandwidth: 50 MHz to 70 GHz
- Insertion Loss: 0.8 dB
- Isolation: 31 dB @ 50 GHz
- Low Current Consumption:
 - -10 mA for Low Loss State
 - +10 mA for Isolation State
- MACOMs Unique AlGaAs Hetero-Junction Anode Technology
- Silicon Nitride Passivation
- Polymer Scratch Protection
- RoHS* Compliant

Applications

- Aerospace & Defense
- ISM

Description

The MA4AGSW3 is an Aluminum-Gallium-Arsenide, single pole, triple throw (SP3T), PIN diode switch. The switch features enhanced AlGaAs anodes which are formed using MACOM's hetero-junction technology. AlGaAs technology produces a switch with less loss than a device fabricated using conventional GaAs processes. As much as a 0.3 dB reduction in insertion loss can be realized at 50 GHz. This device is fabricated on an OMCVD epitaxial wafer using a process designed for high device uniformity and extremely low parasitics. The diodes within the chip exhibit low series resistance, low capacitance, and fast switching speed. They are fully passivated with silicon nitride and have an additional polymer layer for scratch protection. The protective coating prevents damage during handling and assembly to the diode junction and the chip anode air-bridges. Off chip bias circuitry is required.

The high electron mobility of AlGaAs and the low capacitance of the PIN diodes used makes this switch ideal for fast response, high frequency, multi-throw switch designs. AlGaAs PIN diode switches are an ideal choice for switching arrays in radar systems, radiometers, test equipment and other multi-assembly components.



Yellow areas indicate bond pads



Ordering Information

Part Number	Package
MA4AGSW3	waffle pack
MASW-000553-13220G	Gel Pack

* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

1

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.



MA4AGSW3 Rev. V9

Electrical Specifications: $T_A = +25^{\circ}C, \pm 10 \text{ mA Bias Current}^1, \pm 5 \text{ V} \text{ (on-wafer measurements)}$

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Insertion Loss	0.05 - 18 GHz 18 - 50 GHz	dB	_	0.6 0.8	0.7 1.1
Isolation	0.05 - 18 GHz 18 - 50 GHz	dB	38 24	45 31	_
Input Return Loss	0.05 - 18 GHz 18 - 50 GHz	dB	_	21 24	_
Output Return Loss	0.05 - 18 GHz 18 - 50 GHz	dB	—	26 20	_
Switching Speed ² (10 - 90% RF Voltage)	±5 V TTL Compatible PIN Diode Driver, 10 GHz	ns	_	20	_

1. Bias current of ±10 mA is recommended for optimal performance.

Typical switching speed is measured from 10% to 90% of the detected RF voltage driven by a ±5 V TTL compatible driver. Driver output
parallel RC network uses a capacitor between 390 - 560 pF and a resistor between 150 - 220 Ω to achieve 15 ns rise and fall times.

Absolute Maximum Ratings^{3,4,5} @ T_A = +25°C

Parameter	Absolute Maximum
Incident C.W. RF Power	23 dBm
DC Reverse Voltage	25 V
Bias Current	±25 mA
Junction Temperature	+175°C
Operating Temperature	-55°C to +125°C
Storage Temperature	-55°C to +150°C
Assembly Temperature	+300°C < 10 sec.

3. Maximum combined operating conditions for RF Power, DC bias, and temperature: 23 dBm C.W. @ 10 mA (per diode) @ +85°C.

4. Exceeding any one or combination of these limits may cause permanent damage to this device.

5. MACOM does not recommend sustained operation near these survivability limits.

²

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.

SP3T AlGaAs PIN Diode Switch



MA4AGSW3 Rev. V9

Typical RF Performance Curves @ +25°C (probed on wafer)

Insertion Loss @ -10 mA





Input Return Loss @ -10 mA



Output Return Loss @ -10 mA



3

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.

For further information and support please visit: <u>https://www.macom.com/support</u>

SP3T AlGaAs PIN Diode Switch



MA4AGSW3 Rev. V9

Operation of the MA4AGSW3 Switch

The simultaneous application of a negative DC current to the low loss port and positive DC current to the remaining isolated switching port is required for the operation of the MA4AGSW3, AlGaAs, PIN switch. The backside area of the die is the RF and DC return ground plane. The DC return is connected to the common port J1. The forward bias voltage at J2, J3 & J4 will not exceed ± 1.6 V and is typically ± 1.4 V with supply current of ± 10 mA. In the low loss state, the series diode must be forward biased and the shunt diode reverse biased. While for the Isolated port, the shunt diode is forward biased and the series diode is reverse biased. The bias network design shown below should yield >30 dB RF to DC Isolation.

The lowest insertion loss, P1dB, IP3, and switching speed is achieved by using a voltage pull-up resistor in the DC return path, (J1). A minimum value of |-2 V| is recommended at this return node, which is achievable with a standard, ±5 V TTL Controlled PIN Diode Driver.

MA4AGSW3 Schematic with a Typical External 2 - 18 GHz Bias Network



Typical Driver Connections

Control Level (DC Current)			RF Output State			
J2	J3	J4	J2 - J1 J3 - J1		J4 - J1	
-10 mA	+10 mA	+10 mA	Low Loss	Isolation	Isolation	
+10 mA	-10 mA	+10 mA	Isolation	Low Loss	Isolation	
+10 mA	+10 mA	-10 mA	Isolation	Isolation	Low Loss	

4

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.



MA4AGSW3 Rev. V9

MADR-011022 Driver with MA4AGSW3 Switch Application Schematic 2 - 18 GHz



Parts List⁶

Part	Value
C1, C3, C6, C8	0.1 µF
C2, C7	47 pF
C4, C5, C9	470 pF
R1 - R3	320 Ω
R4	500 Ω

6. Resistor values calculated to provide ~10 mA of bias current given V_{CC} = 5 V, V_{EEB} = -10 V, voltage drop at driver output 0.4 V and V_F of switch diodes 1.4 V.

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information. Chip Dimensions and Bonding Pad Locations (In Yellow)

Dimensions	mils			mm		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	52.0	53.0	54.0	1.321	1.346	1.372
В	53.0	54.0	55.0	1.346	1.372	1.397
С	45.0	45.5	46.0	1.143	1.156	1.168
D	21.5	22.0	22.5	0.546	0.559	0.572
E	23.0	23.5	24.0	0.584	0.597	0.610
F	21.5	22.0	22.5	0.546	0.559	0.572
G	3.5	4.0	4.5	0.089	0.102	0.114
Н	3.5	4.0	4.5	0.089	0.102	0.114

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.

ŧ

o o AGPSST J2 \odot 0 D Ó С в ١ o G4X 0 0 G 4X-Е \square F F н



MA4AGSW3 Rev. V9



6



Assembly Instructions

<u>Cleanliness</u>

The chip should be handled in a clean environment.

Static Sensitivity

This device is considered ESD Class 1A, HBM. Proper ESD techniques should be used during handling.

General Handling

The protective polymer coating on the active areas of the die provides scratch and impact protection, particularly for the metal air bridge, which contacts the diode's anode. Die should primarily be handled with vacuum pickup tools, or alternatively with plastic tweezers.

Assembly Techniques

The MA4AGSW3, AlGaAs switch is designed to be mounted with electrically conductive silver epoxy or with a low temperature solder perform, which does not have a rich tin content.

Solder DIE Attach

Only solders which do not scavenge gold, such as 80Au/20Sn or Indalloy #2 is recommended. Do not expose die to temperatures >300°C for more than 10 seconds.

Conductive Epoxy DIE Attach

Use a controlled thickness of approximately 2 mils for best electrical conductivity and lowest thermal resistance. Cure epoxy per manufacturer's schedule. Typically 150°C for 1 hour.

Ribbon/Wire Bonding

Thermo-compression wedge or ball bonding may be used to attach ribbons or wire to the gold bonding pads. A $1/4 \times 3$ mil gold ribbon is recommended on all RF ports and should be kept as short as possible for the lowest inductance and best microwave performance. For more detailed handling and assembly instructions, see Application Note M541, "Bonding and Handling Procedures for Chip Diode Devices" at www.macom.com.

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.



MA4AGSW3 Rev. V9

MACOM Technology Solutions Inc. ("MACOM"). All rights reserved.

These materials are provided in connection with MACOM's products as a service to its customers and may be used for informational purposes only. Except as provided in its Terms and Conditions of Sale or any separate agreement, MACOM assumes no liability or responsibility whatsoever, including for (i) errors or omissions in these materials; (ii) failure to update these materials; or (iii) conflicts or incompatibilities arising from future changes to specifications and product descriptions, which MACOM may make at any time, without notice. These materials grant no license, express or implied, to any intellectual property rights.

THESE MATERIALS ARE PROVIDED "AS IS" WITH NO WARRANTY OR LIABILITY, EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, INFRINGEMENT OF INTELLECTUAL PROPERTY RIGHT, ACCURACY OR COMPLETENESS, OR SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES WHICH MAY RESULT FROM USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.

⁸

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.